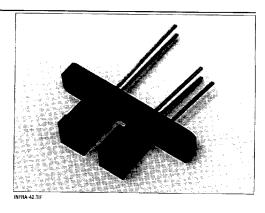
HOA2003

Transmissive Optoschmitt Sensor

FEATURES

- Direct TTL interface
- Buffer logic
- . 0.010 in.(2.54 mm) offset detector leads
- 0.125 in.(3.18 mm) slot width
- Accurate position sensing
- Dust protective housing



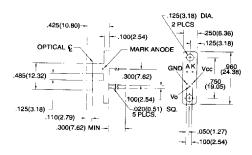
DESCRIPTION

The HOA2003 consists of an infrared emitting diode facing an Optoschmitt detector encased in a black thermoplastic housing. The photodetector consists of a photodiode, amplifier, voltage regulator, Schmitt trigger and an NPN output transistor with 10 k Ω (nominal) pullup resistor. The buffer logic provides a high output when the optical path is clear, and a low output when the path is interrupted. The HOA2003 utilizes an IR transmissive polysulfone housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The detector has a 0.010 in.(.254 mm) x 0.040 in.(1.02 mm) vertical aperture which is ideal for use in applications in which maximum position resolution is desired. The HOA2003 employs plastic molded components. For additional component information see SEP8506 and SDP8600.

Housing material is polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals $\pm 0.010(0.25)$ 2 plc decimals $\pm 0.020(0.51)$



DIM_064.cdr





Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

HOA2003

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ELECTRICAL CHARACTERISTIC (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	٧	I _F =20 mA
Reverse Leakage Current	I _B			10	μA	V _R =3 V
DETECTOR						
Operating Supply Voltage	Vcc	4.5		10	v	
Low Level Supply Current	ICCL	4.0		12	mA	Vcc=5 V
		5.0		15		V _{CC} =12 V
High Level Supply Current	Іссн	2.0		10	mA	Vcc=5 V
		3.0		12		Vcc=12 V
Low Level Output Voltage	Vol	Ì		0.4	v	I _{OL} =12.8 mA, I _F =0 mA
High Level Output Voltage	Voн	2.4			v	I _{OH} =0, I _F =20 mA
Hysteresis (2)	HYST	i	10		%	
Propagation Delay, Low-High	t _{PLH}	1	5		μs	Vcc=5 V, I _F =20 mA
Propagation Delay, High-Low	tpHL	Ī	5		μs	Vcc=5 V, I _F =20 mA
Rise Time	tr		60		ns	R _L =390 Ω, C _L =50 pF
Fall Time	t,	Ì	15		ns	R _L =390 Ω, C _L =50 pF
COUPLED CHARACTERISTICS		1		***************************************		
IRED Trigger Current	let.				mA	V _{cc=5} V
HOA2003-001		1		20		

- 1. It is recommended that a bypass capacitor, 0.1 μF typical, be added between Vcc and GND near the device in order to stabilize power supply line.
- 2. Hysteresis is defined as the difference between the operating and release threshold intensities, expressed as a percentage of the operate threshold intensity.

ABSOLUTE MAXIMUM RATINGS (25°C Free-Air Temperature unless otherwise noted)

-40°C to 70°C Operating Temperature Range

Storage Temperature Range -40°C to 85°C 240°C Soldering Temperature (5 sec)

IR EMITTER

100 mW (1) Power Dissipation 3 V Reverse Voltage Continuous Forward Current 50 mA DETECTOR

Supply Voltage Output Sink Current

Duration of Output

Short to Vcc or Ground

12 V (2) 18 mA

1.0 sec.

Notes

- 1. Derate linearly at 0.78 mW/°C above 25°C.
- 2. Derate linearly from 25°C to 5.5 V at 70°C

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Anode

Cathode



SCHEMATIC Q Vcc

Ó GND

Voltage

regulator

HOA2003

Transmissive Optoschmitt Sensor

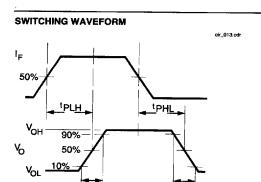
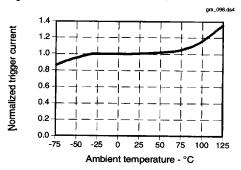
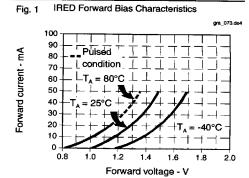


Fig. 2 IRED Trigger Current vs Temperature



All Performance Curves Show Typical Values



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